

2SK4145A

N-channel MOSFET 60 V, 84 A, 10 m Ω

R07DS0880EC0101 Rev.1.00 Apr 17, 2013

Description

The 2SK4145A is N-channel MOS Field Effect Transistor designed for high current switching applications.

Features

• Low on-state resistance

 $R_{DS (on)} = 10 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, I_D = 42 \text{ A})$

• Low input capacitance

 $C_{iss} = 3310 \text{ pF TYP}. (V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V})$

• High current

 $I_{D(DC)} = \pm 84 \text{ A}$

• RoHS Compliant

Ordering Information

Part No.	Lead Plating		Packing		Package
2SK4145A-S19-AY/LMV *1	Pure Sn (Tin)	Tube	50 p/tube	TO-220	2.0 g TYP.
2SK4145A-S19-AY/LCV *1	Pure Sn (Tin)	Tube	50 p/tube	TO-220	2.0 g TYP.

Note: *1. Pb-free (This product does not contain Pb in the external electrode.)

Absolute Maximum Ratings (T_A = 25°C, all terminals are connected)

Item	Symbol	Ratings	Unit
Drain to Source Voltage ($V_{GS} = 0 V$)	V _{DSS}	60	V
Gate to Source Voltage ($V_{DS} = 0 V$)	V _{GSS}	±20	V
Drain Current (DC)	I _{D(DC)}	±84	А
Drain Current (pulse) *1	I _{D(pulse)}	±215	A
Total Power Dissipation ($T_C = 25^{\circ}C$)	P _{T1}	84	W
Total Power Dissipation ($T_A = 25^{\circ}C$)	P _{T2}	1.5	W
Channel Temperature	T _{ch}	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C
Single Avalanche Current *2	I _{AS}	36	А
Single Avalanche Energy *2	E _{AS}	130	mJ

Thermal Resistance

Channel to Case (Drain) Thermal Resistance	R _{th(ch-C)}	1.49	°C/W
Channel to Ambient Thermal Resistance *2	R _{th(ch-A)}	83.3	°C/W

Notes: *1. PW \leq 10 μ s, Duty Cycle \leq 1%

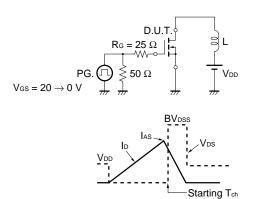
*2. Starting T_{ch} = 25°C, R_G = 25 Ω , V_{DD} = 30 V, V_{GS} = 20 \rightarrow 0 V, L = 100 μ H



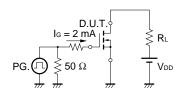
ltem	Symbol	MIN.	TYP.	MAX.	Unit	Test Conditions
Zero Gate Voltage Drain Current	I _{DSS}			10	μA	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$
Gate Leakage Current	I _{GSS}			±100	nA	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{V}$
Gate to Source Cut-off Voltage	V _{GS(off)}	2.0	3.0	4.0	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Forward Transfer Admittance *1	y _{fs}	16	36		S	$V_{DS} = 10 \text{ V}, I_D = 30 \text{ A}$
Drain to Source On-state Resistance * ¹	R _{DS(on)}		7.2	10	mΩ	$V_{GS} = 10 \text{ V}, I_D = 42 \text{ A}$
Input Capacitance	C _{iss}		3310		pF	V _{DS} = 10 V,
Output Capacitance	C _{oss}		610		pF	$V_{GS} = 0 V,$
Reverse Transfer Capacitance	C _{rss}		340		pF	f =1 MHz
Turn-on Delay Time	t _{d(on)}		19		ns	$V_{DD} = 30 \text{ V}, I_D = 42 \text{ A},$
Rise Time	tr		14		ns	V _{GS} =10 V,
Turn-off Delay Time	t _{d(off)}		59		ns	$R_G = 0 \Omega$
Fall Time	t _f		11		ns	
Total Gate Charge	Q _G		66		nC	V _{DD} = 48 V,
Gate to Source Charge	Q _{GS}		12		nC	V _{GS} = 10 V,
Gate to Drain Charge	Q _{GD}		24		nC	I _D = 84 A
Body Diode Forward Voltage *1	V _{F(S-D)}		1.0	1.5	V	$I_F = 84 \text{ A}, V_{GS} = 0 \text{ V}$
Reverse Recovery Time	t _{rr}		44		ns	$I_F = 84 \text{ A}, V_{GS} = 0 \text{ V},$
Reverse Recovery Charge	Qrr		59		nC	di/dt = 100 A/µs

Note: *1. Pulsed

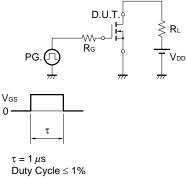
TEST CIRCUIT 1 AVALANCHE CAPABILITY

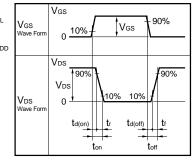


TEST CIRCUIT 3 GATE CHARGE



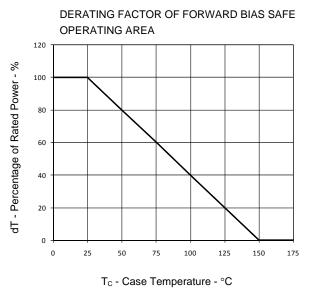
TEST CIRCUIT 2 SWITCHING TIME

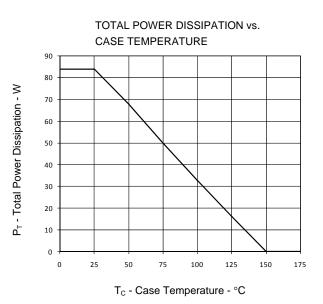




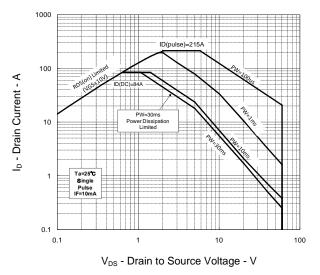


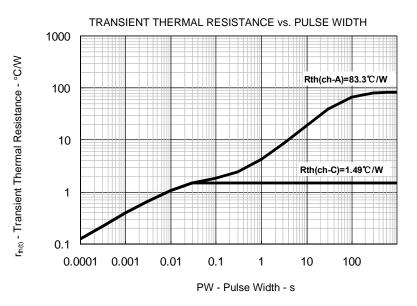
Typical Characteristics (T_A = 25°C)

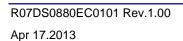




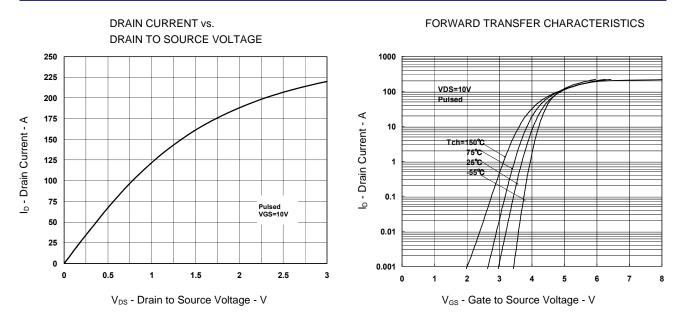
FORWARD BIAS SAFE OPERATING AREA



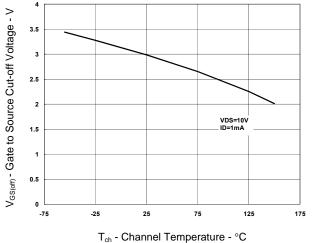


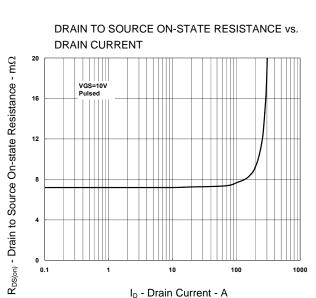




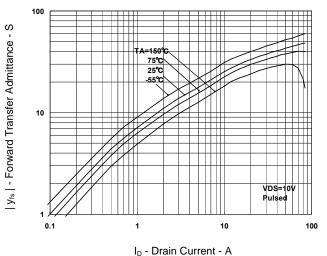


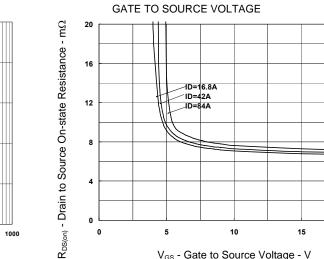
GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



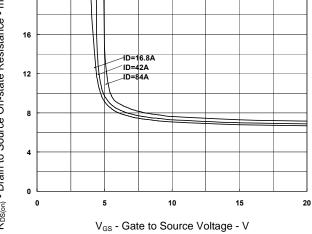


FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

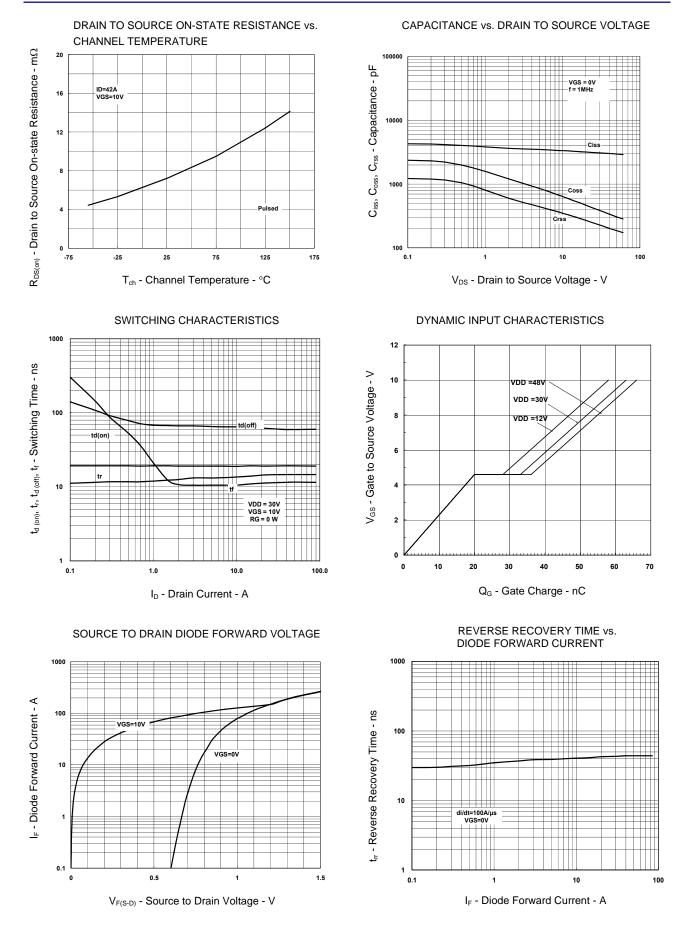




DRAIN TO SOURCE ON-STATE RESISTANCE vs.



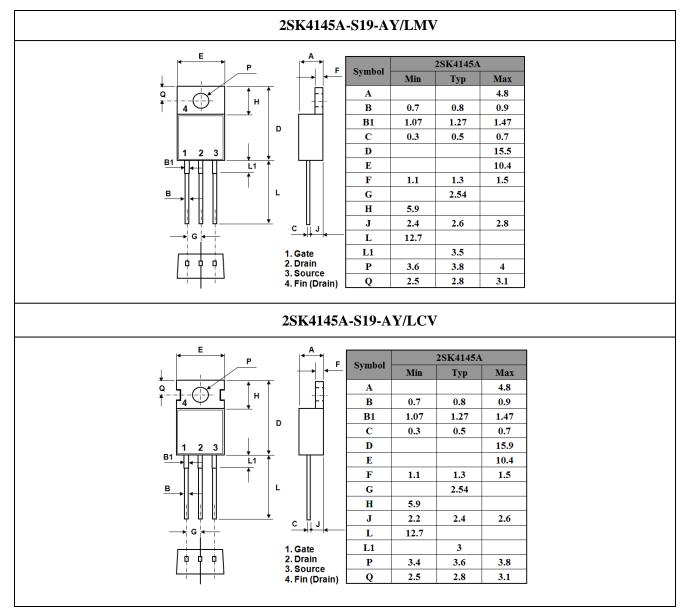




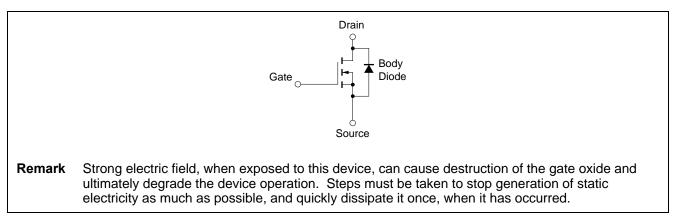


Package Drawing (Unit: mm)

TO-220



Equivalent Circuit





2SK4145A Data Sheet

		Description				
Rev.	Date	Page	Summary			
1.00	Apr 17, 2013	-	First Edition Issued			

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